

# Isc N-Channel MOSFET Transistor

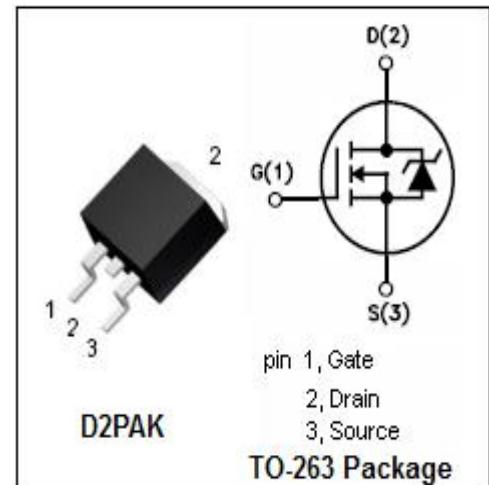
# RU75230S

## • FEATURES

- With To-263(D2PAK) package
- Ultra low on-resistance
- Fast Switching Speed
- High power and current handling capability
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## • APPLICATIONS

- High current switching applications
- DC-DC convertors

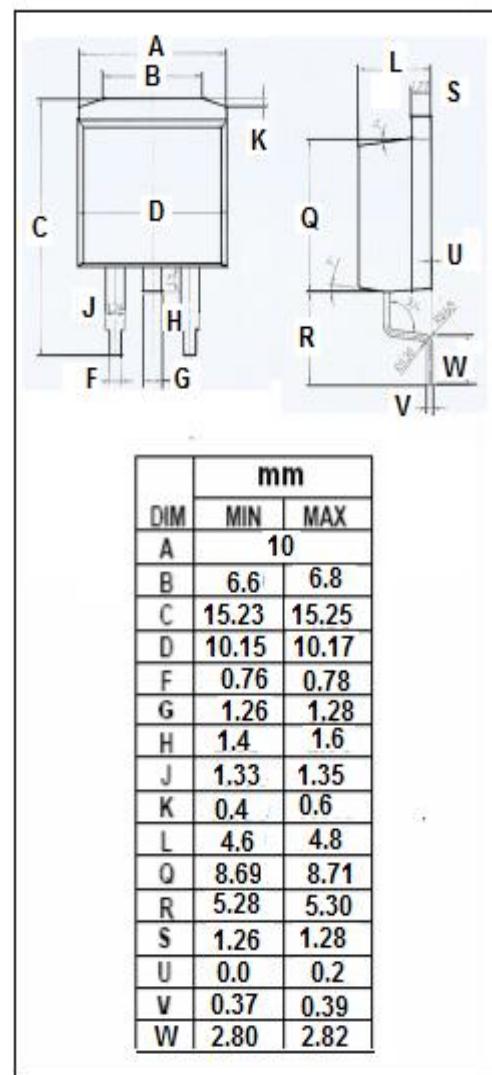


## • ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	75	V
$V_{GSS}$	Gate-Source Voltage	$\pm 25$	V
$I_D$	Drain Current-Continuous@ $T_c=25^\circ\text{C}$ $T_c=125^\circ\text{C}$	230 163	A
$I_{DM}$	Drain Current-Single Pulsed	920	A
$P_D$	Total Dissipation @ $T_c=25^\circ\text{C}$ $T_c=125^\circ\text{C}$	333 167	W
$T_{ch}$	Max. Operating Junction Temperature	175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~175	$^\circ\text{C}$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.45	$^\circ\text{C}/\text{W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62.5	$^\circ\text{C}/\text{W}$



**Isc N-Channel MOSFET Transistor****RU75230S****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}; I_{\text{D}}= 0.25\text{mA}$	75			V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}= \pm 25\text{V}; I_{\text{D}}=0.25\text{mA}$	2		4	V
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$V_{\text{GS}}= 10\text{V}; I_{\text{D}}=75\text{A}$		2.6	3	$\text{m}\Omega$
$I_{\text{GSS}}$	Gate-Source Leakage Current	$V_{\text{GS}}= \pm 25\text{V}; V_{\text{DS}}= 0\text{V}$			$\pm 0.1$	$\mu\text{ A}$
$I_{\text{DSS}}$	Drain-Source Leakage Current	$V_{\text{DS}}=75\text{V}; V_{\text{GS}}= 0\text{V}; T_J=25^\circ\text{C}$ $T_J=125^\circ\text{C}$			1 30	$\mu\text{ A}$
$V_{\text{SDF}}$	Diode forward voltage	$I_{\text{SD}}=75\text{A}, V_{\text{GS}} = 0 \text{ V}$			1.2	V

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